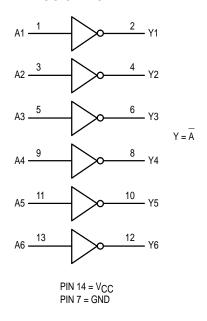
# **Hex Unbuffered Inverter**High-Performance Silicon-Gate CMOS

The MC74HCU04 is identical in pinout to the LS04 and the MC14069UB. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

This device consists of six single–stage inverters. These inverters are well suited for use as oscillators, pulse shapers, and in many other applications requiring a high–input impedance amplifier. For digital applications, the HC04 is recommended.

- Output Drive Capability: 10 LSTTL Loads
- · Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2 to 6 V; 2.5 to 6 V in Oscillator Configurations
- Low Input Current: 1 μA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 12 FETs or 3 Equivalent Gates

#### LOGIC DIAGRAM



### MC74HCU04



N SUFFIX PLASTIC PACKAGE CASE 646–06



**D SUFFIX** SOIC PACKAGE CASE 751A-03

#### ORDERING INFORMATION

MC74HCUXXN Plastic MC74HCUXXD SOIC

### PIN ASSIGNMENT

A1 [	1 ●	14	P v <sub>cc</sub>
Y1 [	2	13	A6
A2 [	3	12	□ Y6
Y2 [	4	11	A5
A3 [	5	10	Y5
Y3 [	6	9	A4
GND [	7	8	Y4

#### **FUNCTION TABLE**

Inputs	Outputs	
A	Y	
L H	H	

#### MC74HCU04

#### **MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit
VCC	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V <sub>in</sub>	DC Input Voltage (Referenced to GND)	- 1.5 to V <sub>CC</sub> + 1.5	V
V <sub>out</sub>	DC Output Voltage (Referenced to GND)	- 0.5 to V <sub>CC</sub> + 0.5	V
l <sub>in</sub>	DC Input Current, per Pin	± 20	mA
l <sub>out</sub>	DC Output Current, per Pin	± 25	mA
ICC	DC Supply Current, V <sub>CC</sub> and GND Pins	± 50	mA
PD	Power Dissipation in Still Air Plastic DIP† SOIC Package†	750 500	mW
T <sub>stg</sub>	Storage Temperature	- 65 to + 150	°C
TL	Lead Temperature, 1 mm from case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range GND  $\leq$  ( $V_{in}$  or  $V_{out}$ )  $\leq$  VCC. Unused inputs must always be tied to an appropriate logic voltage

level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

SOIC Package: -7mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
VCC	DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Referenced to GND)	0	Vcc	V
TA	Operating Temperature, All Package Types	- 55	+ 125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Figure 1)	-	No Limit	ns

#### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

		Guaranteed Limit		mit				
Symbol	Parameter	Test Co	onditions	V <sub>CC</sub>	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
VIH	Minimum High-Level Input Voltage	$V_{out} = 0.5 \text{ V}^*$ $ I_{out}  \le 20 \mu\text{A}$		2.0 4.5 6.0	1.7 3.6 4.8	1.7 3.6 4.8	1.7 3.6 4.8	V
VIL	Maximum Low–Level Input Voltage	$V_{\text{out}} = V_{\text{CC}} - 0.$ $ I_{\text{out}}  \le 20 \mu\text{A}$	5 V*	2.0 4.5 6.0	0.3 0.8 1.1	0.3 0.8 1.1	0.3 0.8 1.1	V
VOH	Minimum High–Level Output Voltage	$V_{in} = GND$ $ I_{Out}  \le 20 \mu A$		2.0 4.5 6.0	1.8 4.0 5.5	1.8 4.0 5.5	1.8 4.0 5.5	V
		V <sub>in</sub> = GND	$ I_{Out}  \le 4.0 \text{ mA}$ $ I_{Out}  \le 5.2 \text{ mA}$	4.5 6.0	3.86 5.36	3.76 5.26	3.70 5.20	
VOL	Maximum Low–Level Output Voltage	$V_{\text{in}} = V_{\text{CC}}$ $ I_{\text{Out}}  \le 20 \mu\text{A}$		2.0 4.5 6.0	0.2 0.5 0.5	0.2 0.5 0.5	0.2 0.5 0.5	V
		V <sub>in</sub> = V <sub>CC</sub>	$ I_{out}  \le 4.0 \text{ mA}$ $ I_{out}  \le 5.2 \text{ mA}$	4.5 6.0	0.32 0.32	0.37 0.37	0.40 0.40	
l <sub>in</sub>	Maximum Input Leakage Current	V <sub>in</sub> = V <sub>CC</sub> or GN	ND	6.0	± 0.1	± 1.0	± 1.0	μΑ
lcc	Maximum Quiescent Supply Current (per Package)	V <sub>in</sub> = V <sub>CC</sub> or GN I <sub>out</sub> = 0 μA	ND	6.0	2	20	40	μΑ

NOTE: Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

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<sup>\*</sup> Maximum Ratings are those values beyond which damage to the device may occur.

Functional operation should be restricted to the Recommended Operating Conditions.

<sup>†</sup>Derating — Plastic DIP: -10mW/°C from 65° to 125°C

<sup>\*</sup> For  $V_{CC}$  = 2.0 V,  $V_{out}$  = 0.2 V or  $V_{CC}$  – 0.2 V.

#### AC ELECTRICAL CHARACTERISTICS ( $C_L = 50 \text{ pF}$ , Input $t_f = t_f = 6 \text{ ns}$ )

			Guaranteed Limit			
Symbol	Parameter	v <sub>CC</sub>	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Input A to Output Y (Figures 1 and 2)	2.0 4.5 6.0	80 16 14	100 20 17	120 24 20	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, Any Output (Figures 1 and 2)	2.0 4.5 6.0	75 15 13	95 19 16	110 22 19	ns
C <sub>in</sub>	Maximum Input Capacitance	_	10	10	10	pF

#### NOTES:

- For propagation delays with loads other than 50 pF, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).
   Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

		Typical @ 25°C, V <sub>CC</sub> = 5.0 V	
C <sub>PD</sub>	Power Dissipation Capacitance (Per Inverter)*	15	pF

<sup>\*</sup> Used to determine the no–load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ . For load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

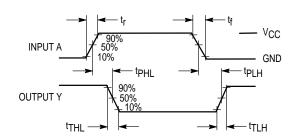
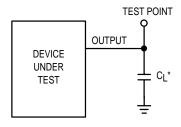


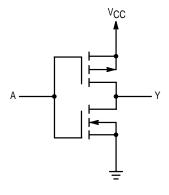
Figure 1. Switching Waveforms



\* Includes all probe and jig capacitance

Figure 2. Test Circuit

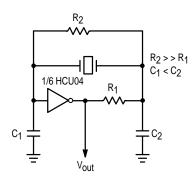
#### **LOGIC DETAIL** (1/6 of Device Shown)



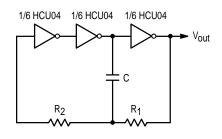
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#### **TYPICAL APPLICATIONS**

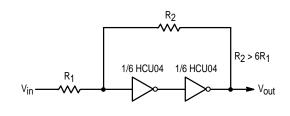
#### **Crystal Oscillator**



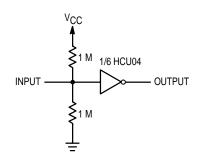
#### Stable RC Oscillator



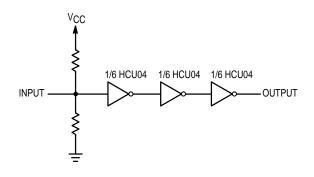
#### **Schmitt Trigger**



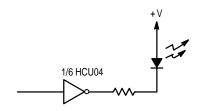
## High Input Impedance Single-Stage Amplifier with a 2 to 6 V Supply Range



#### Multi-Stage Amplifier



#### **LED Driver**



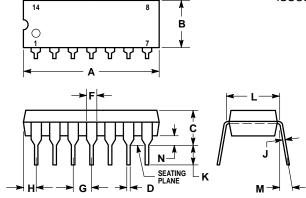
For reduced power supply current, use high–efficiency LEDs such as the Hewlett–Packard HLMP series or equivalent.

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#### **OUTLINE DIMENSIONS**

#### **N SUFFIX**

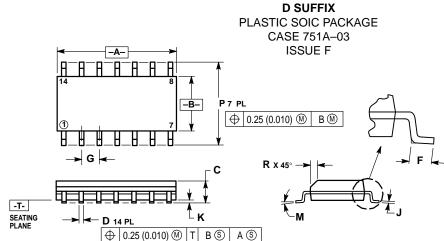
PLASTIC DIP PACKAGE CASE 646-06 ISSUF I



#### NOTES:

- LEADS WITHIN 0.13 (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD
- ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	19.56	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100	BSC	2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
K	0.115	0.135	2.92	3.43	
L	0.300 BSC		7.62 BSC		
M	0°	10°	0°	10°	
N	0.015	0.039	0.39	1.01	



- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- PER SIDE.
  DIMENSION D DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.127 (0.005) TOTAL
  IN EXCESS OF THE D DIMENSION AT

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	8.55	8.75	0.337	0.344	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050	BSC	
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
Р	5.80	6.20	0.228	0.244	
R	0.25	0.50	0.010	0.019	

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